

TOSHIBA Photocoupler GaAs Ired & Photo-Transistor

TLP120

Programmable Controllers

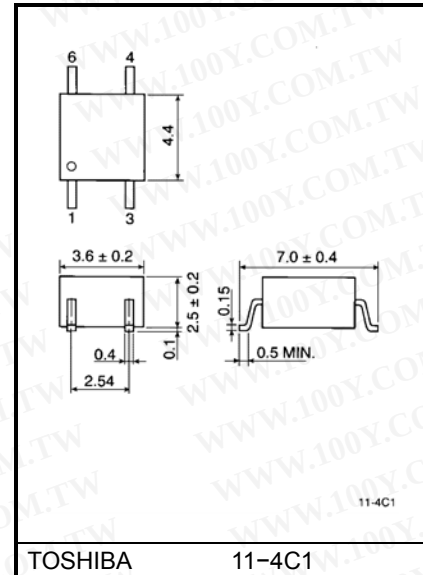
AC / DC-Input Module

Telecommunication

The TOSHIBA mini flat coupler TLP120 is a small outline coupler, suitable for surface mount assembly. TLP120 consists of a photo transistor, optically coupled to two gallium arsenide infrared emitting diode connected inverse parallel, and can operate directly by AC input current.

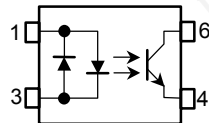
- Collector-emitter voltage: 80 V (min.)
- Current transfer ratio: 50% (min.)
Rank GB: 100% (min.)
- Isolation voltage: 3750Vrms (min.)
- UL recognized: UL1577, file no. E67349

Unit in mm



Weight: 0.09 g

Pin Configurations (top view)



- 1 : Anode
- 3 : Cathode
- 4 : Emitter
- 6 : Collector

勝特力材料 886-3-5753170
 勝特力电子(上海) 86-21-54151736
 勝特力电子(深圳) 86-755-83298787
[Http://www.100y.com.tw](http://www.100y.com.tw)

Maximum Ratings (Ta = 25°C)

Characteristic		Symbol	Rating	Unit
LED	Forward current	$I_{F(RMS)}$	50	mA
	Forward current derating	$\Delta I_F / ^\circ C$	-0.7 (Ta $\geq 53^\circ C$)	mA / $^\circ C$
	Pulse forward current	I_{FP}	1 (100 μ s pulse, 100pps)	A
	Junction temperature	T_j	125	$^\circ C$
Detector	Collector-emitter voltage	V_{CEO}	80	V
	Emitter-collector voltage	V_{ECO}	7	V
	Collector current	I_C	50	mA
	Collector power dissipation	P_C	150	mW
	Collector power dissipation derating (Ta $\geq 25^\circ C$)	$\Delta P_C / ^\circ C$	-1.5	mW / $^\circ C$
	Junction temperature	T_j	125	$^\circ C$
Storage temperature range		T_{stg}	-55~125	$^\circ C$
Operating temperature range		T_{opr}	-55~100	$^\circ C$
Lead soldering temperature		T_{sol}	260 (10s)	$^\circ C$
Total package power dissipation		P_T	200	mW
Total package power dissipation derating (Ta $\geq 25^\circ C$)		$\Delta P_T / ^\circ C$	-2.0	mW / $^\circ C$
Isolation voltage (Note 1)		BV_S	3750 (AC, 1min., R.H. $\leq 60\%$)	Vrms

(Note 1) Device considered a two terminal device: Pins1, 3 shorted together and pins 4, 6 shorted together.

Recommended Operating Conditions

Characteristic	Symbol	Min.	Typ.	Max.	Unit
Supply voltage	V_{CC}	—	5	48	V
Forward current	$I_{F(RMS)}$	—	16	20	mA
Collector current	I_C	—	1	10	mA
Operating temperature	T_{opr}	-25	—	85	$^\circ C$

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Individual Electrical Characteristics (Ta = 25°C)

Characteristic		Symbol	Test Condition	Min.	Typ.	Max.	Unit
LED	Forward voltage	V_F	$I_F = \pm 10 \text{ mA}$	1.0	1.15	1.3	V
	Capacitance	C_T	$V = 0, f = 1 \text{ MHz}$	—	60	—	pF
Detector	Collector-emitter breakdown voltage	$V_{(BR)CEO}$	$I_C = 0.5 \text{ mA}$	80	—	—	V
	Emitter-collector breakdown voltage	$V_{(BR)ECO}$	$I_E = 0.1 \text{ mA}$	7	—	—	V
	Collector dark current	I_{CEO}	$V_{CE} = 48 \text{ V}$	—	10	100	nA
			$V_{CE} = 48 \text{ V}, T_a = 85^\circ\text{C}$	—	2	50	μA
	Capacitance (collector to emitter)	C_{CE}	$V = 0, f = 1 \text{ MHz}$	—	10	—	pF

Coupled Electrical Characteristics (Ta = 25°C)

Characteristic	Symbol	Test Condition	Min.	Typ.	Max.	Unit
Current transfer ratio	I_C / I_F	$I_F = \pm 5 \text{ mA}, V_{CE} = 5 \text{ V}$ Rank GB	50	—	600	%
			100	—	600	
Saturated CTR	$I_C / I_F (\text{sat})$	$I_F = \pm 1 \text{ mA}, V_{CE} = 0.4 \text{ V}$ Rank GB	—	60	—	%
			30	—	—	
Collector-emitter saturation voltage	$V_{CE (\text{sat})}$	$I_C = 2.4 \text{ mA}, I_F = \pm 8 \text{ mA}$	—	—	0.4	V
		$I_C = 0.2 \text{ mA}, I_F = \pm 1 \text{ mA}$ Rank GB	—	0.2	—	
			—	—	0.4	
Off-state collector current	$I_{C(\text{off})}$	$V_F = \pm 0.7 \text{ V}, V_{CE} = 48 \text{ V}$	—	1	10	μA
CTR symmetry	$I_C (\text{ratio})$	$I_C (I_F = -5 \text{ mA}) / I_C (I_F = 5 \text{ mA})$	0.33	1	3	—

Isolation Characteristics (Ta = 25°C)

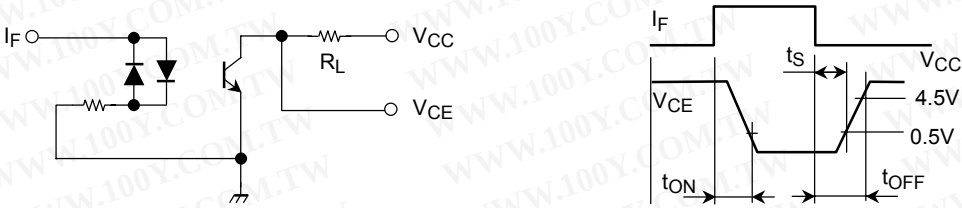
Characteristic	Symbol	Test Condition	Min.	Typ.	Max.	Unit
Capacitance (input to output)	C_S	$V_S = 0, f = 1 \text{ MHz}$	—	0.8	—	pF
Isolation resistance	R_S	$V_S = 500 \text{ V}, \text{R.H.} \leq 60\%$	5×10^{10}	10^{14}	—	Ω
Isolation voltage	BV_S	AC, 1 minute	3750	—	—	V_{rms}
		AC, 1 second, in oil	—	10000	—	
		DC, 1 minute, in oil	—	10000	—	V_{dc}

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Switching Characteristics (Ta = 25°C)

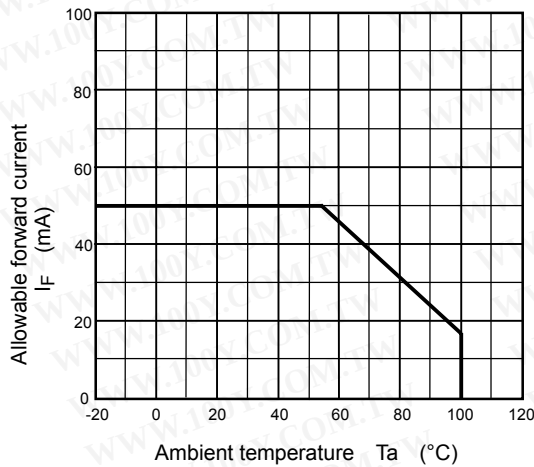
Characteristic	Symbol	Test Condition	Min.	Typ.	Max.	Unit
Rise time	t_r	$V_{CC} = 10\text{ V}, I_C = 2\text{ mA}$ $R_L = 100\Omega$	—	2	—	μs
Fall time	t_f		—	3	—	
Turn-on time	t_{on}		—	3	—	
Turn-off time	t_{off}		—	3	—	
Turn-on time	t_{ON}	$R_L = 1.9\text{ k}\Omega$ $V_{CC} = 5\text{ V}, I_F = \pm 16\text{ mA}$ (Fig.1)	—	2	—	μs
Storage time	t_s		—	25	—	
Turn-off time	t_{OFF}		—	40	—	

Fig. 1 Switching time test circuit

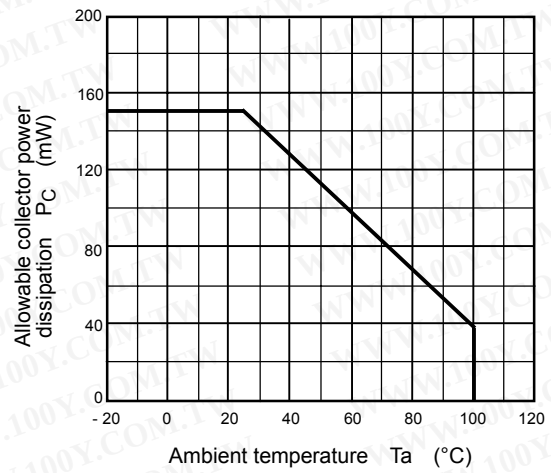


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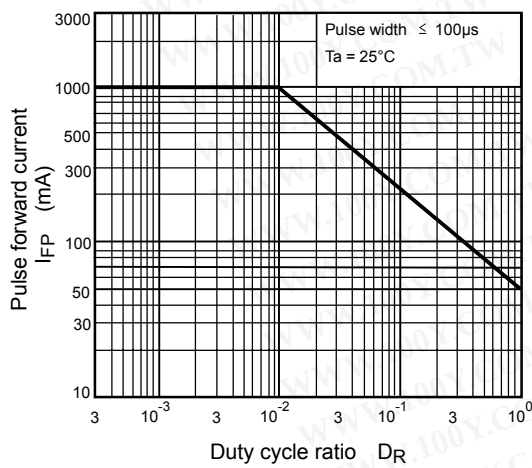
$I_F - T_a$



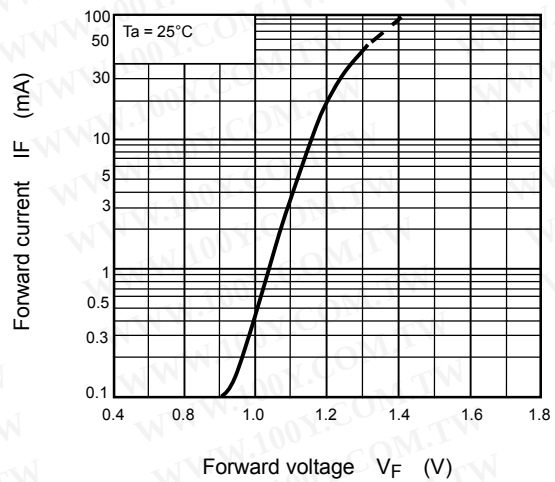
$P_C - T_a$



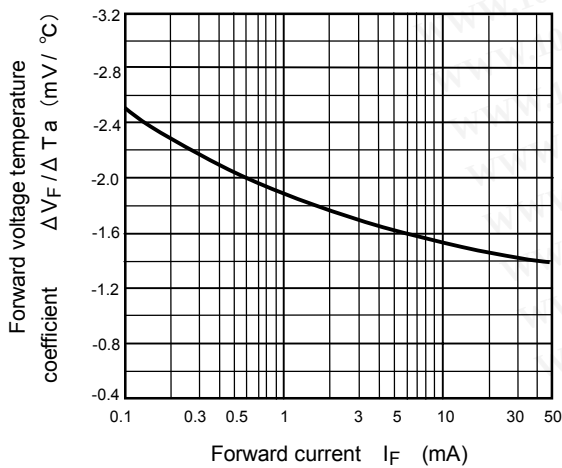
$I_{FP} - D_R$



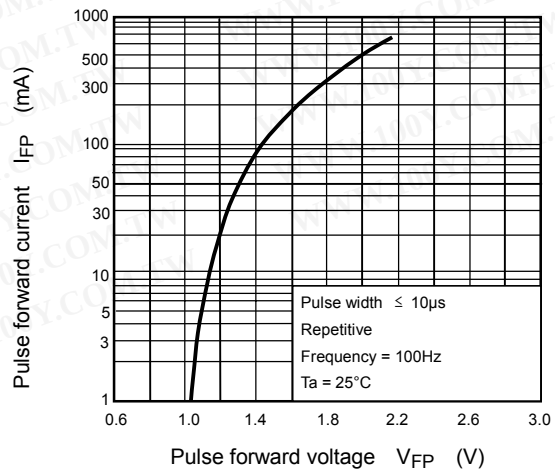
$I_F - V_F$

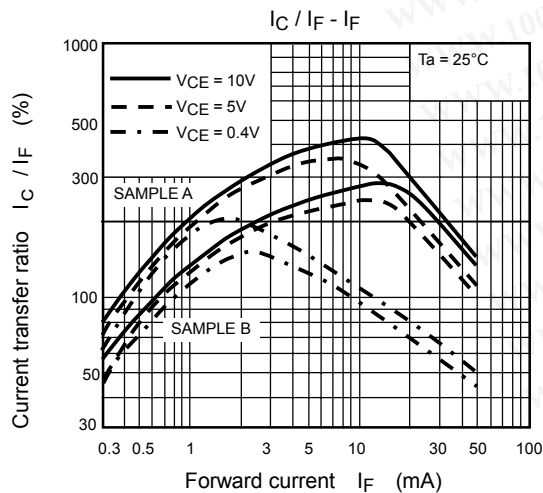
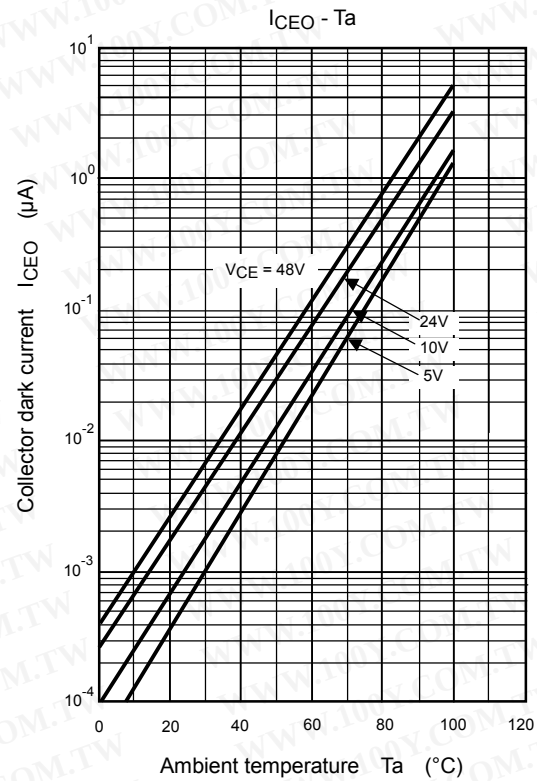
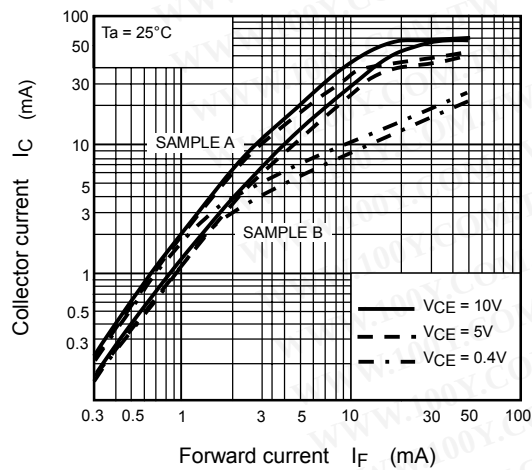
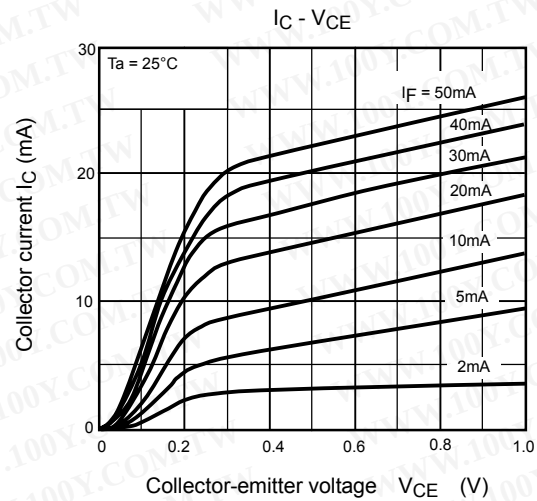
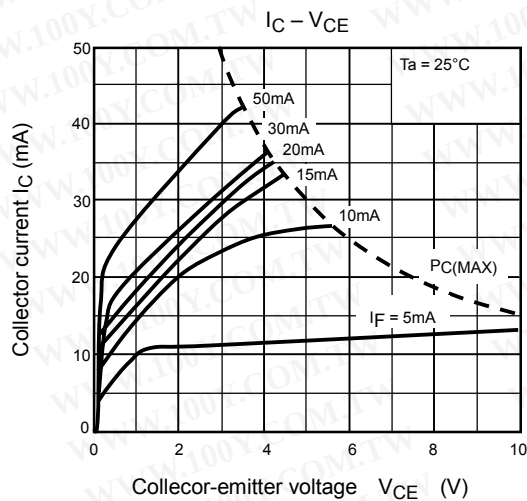


$\Delta V_F / \Delta T_a - I_F$

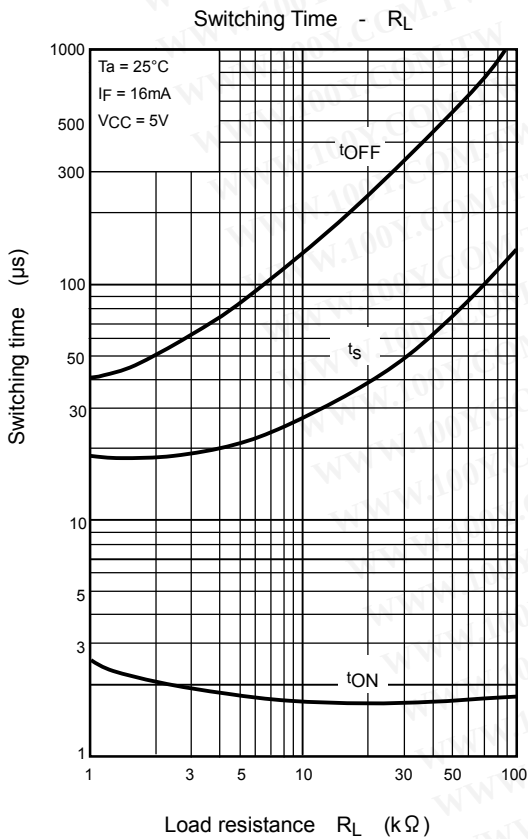
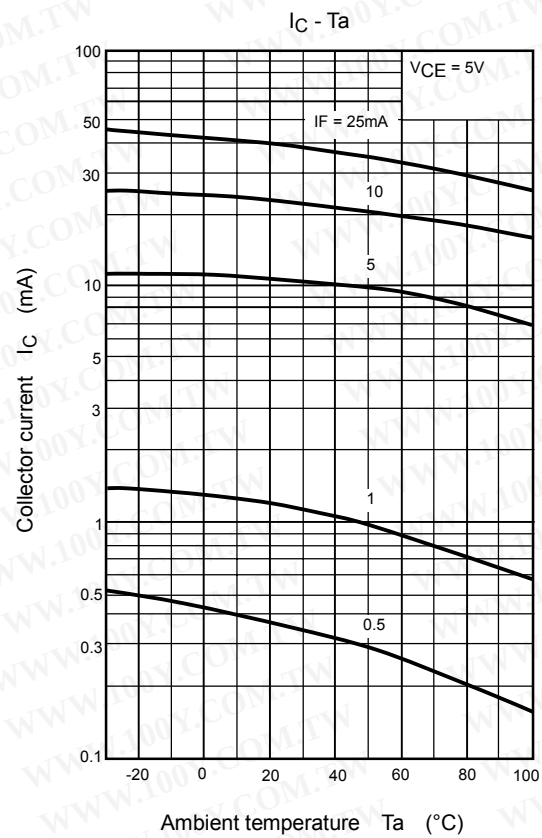
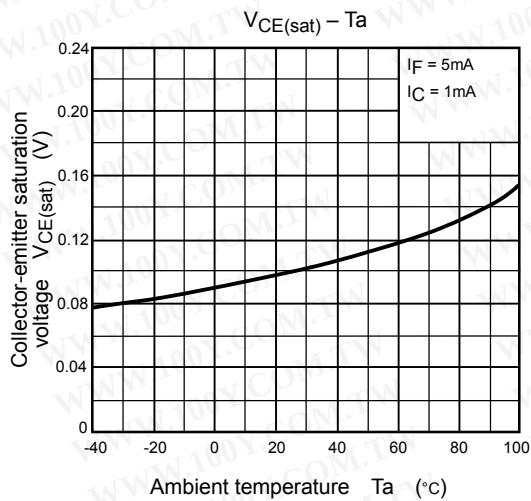


$I_{FP} - V_{FP}$





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